# PNP - 2N6040, 2N6042, NPN - 2N6043, 2N6045

# Plastic Medium-Power Complementary Silicon Transistors

Plastic medium-power complementary silicon transistors are designed for general-purpose amplifier and low-speed switching applications.

## Features

- High DC Current Gain  $-h_{FE} = 2500$  (Typ) @  $I_C = 4.0$  Adc
- Collector-Emitter Sustaining Voltage @ 100 mAdc -V<sub>CEO(sus)</sub> = 60 Vdc (Min) - 2N6040, 2N6043 = 100 Vdc (Min) - 2N6042, 2N6045
- Low Collector-Emitter Saturation Voltage -
  - $V_{CE(sat)} = 2.0 \text{ Vdc} (Max) @ I_C = 4.0 \text{ Adc} 2N6043,44$ = 2.0 Vdc (Max) @ I\_C = 3.0 Adc - 2N6042, 2N6045
- Monolithic Construction with Built–In Base–Emitter Shunt Resistors
- Epoxy Meets UL 94 V–0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V Machine Model, C > 400 V
- These Devices are Pb-Free and are RoHS Compliant\*

#### MAXIMUM RATINGS (Note 1)

Rating		Symbol	Value	Unit
Collector-Emitter Voltage	2N6040 2N6043 2N6042	V <sub>CEO</sub>	60 100	Vdc
	2N6045			
Collector-Base Voltage	2N6040 2N6043	V <sub>CB</sub>	60	Vdc
	2N6042 2N6045		100	
Emitter-Base Voltage		$V_{EB}$	5.0	Vdc
Collector Current	Continuous Peak	Ι <sub>C</sub>	8.0 16	Adc
Base Current		Ι <sub>Β</sub>	120	mAdc
Total Power Dissipation @ To Derate above 25°C	$C = 25^{\circ}C$	PD	75 0.60	W W/∘C
Operating and Storage Junct Temperature Range	tion	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

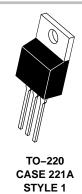
1. Indicates JEDEC Registered Data.

ON

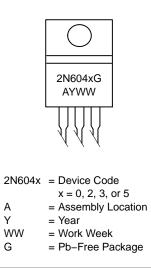
## **ON Semiconductor®**

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# DARLINGTON, 8 AMPERES COMPLEMENTARY SILICON POWER TRANSISTORS 60 – 100 VOLTS, 75 WATTS



## MARKING DIAGRAM



#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# PNP - 2N6040, 2N6042, NPN - 2N6043, 2N6045

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	θJC	1.67	°C/W
Thermal Resistance, Junction-to-Ambient	θ <sub>JA</sub>	57	°C/W

#### \*ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = $25^{\circ}$ C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage $(I_C = 100 \text{ mAdc}, I_B = 0)$	2N6040, 2N6043 2N6042, 2N6045	V <sub>CEO(sus)</sub>	60 100		Vdc
Collector Cutoff Current $(V_{CE} = 60 \text{ Vdc}, I_B = 0)$ $(V_{CE} = 100 \text{ Vdc}, I_B = 0)$	2N6040, 2N6043 2N6042, 2N6045	I <sub>CEO</sub>		20 20	μΑ
	2N6040, 2N6043 2N6042, 2N6045 2N6040, 2N6043 2N6041, 2N6044 2N6042, 2N6045	I <sub>CEX</sub>	- - - -	20 20 200 200 200	μΑ
Collector Cutoff Current $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 100 \text{ Vdc}, I_E = 0)$	2N6040, 2N6043 2N6042, 2N6045	Ісво		20 20	μΑ
Emitter Cutoff Current ( $V_{BE} = 5.0 \text{ Vdc}, I_C = 0$ )		I <sub>EBO</sub>	-	2.0	mAdc

#### **ON CHARACTERISTICS**

$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = 4.0 \; \text{Adc}, \; \text{V}_{CE} = 4.0 \; \text{Vdc}) \\ (I_{C} = 3.0 \; \text{Adc}, \; \text{V}_{CE} = 4.0 \; \text{Vdc}) \\ (I_{C} = 8.0 \; \text{Adc}, \; \text{V}_{CE} = 4.0 \; \text{Vdc}) \end{array} $	2N6040, 2N6043, 2N6042, 2N6045 All Types	h <sub>FE</sub>	1000 1000 100	20.000 20,000 -	-
	2N6040, 2N6043, 2N6042, 2N6045 All Types	V <sub>CE(sat)</sub>		2.0 2.0 4.0	Vdc
Base–Emitter Saturation Voltage ( $I_C = 8.0 \text{ Adc}, I_B = 80 \text{ mAdc}$ )		V <sub>BE(sat)</sub>	-	4.5	Vdc
Base–Emitter On Voltage ( $I_C$ = 4.0 Adc, $V_{CE}$ = 4.0 Vdc)		V <sub>BE(on)</sub>	_	2.8	Vdc

#### DYNAMIC CHARACTERISTICS

Small Signal Current Gain ( $I_C$ = 3.0 Adc, $V_{CE}$ = 4.0 Vdc, f = 1.0 MHz)		h <sub>fe</sub>	4.0	-	
Output Capacitance ( $V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 0.1 \text{ MHz}$ )	2N6040/2N6042 2N6043/2N6045	C <sub>ob</sub>		300 200	pF
Small–Signal Current Gain ( $I_C$ = 3.0 Adc, $V_{CE}$ = 4.0 Vdc, f = 1.0 kHz)		h <sub>fe</sub>	300	-	-

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*Indicates JEDEC Registered Data.

## PNP – 2N6040, 2N6042, NPN – 2N6043, 2N6045

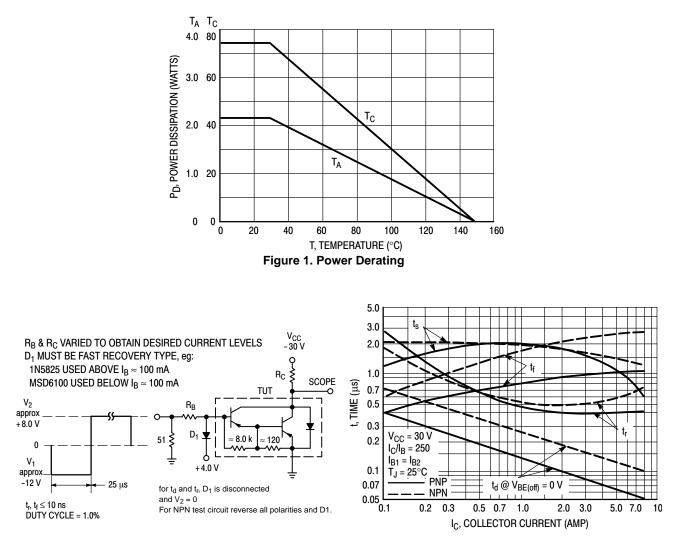
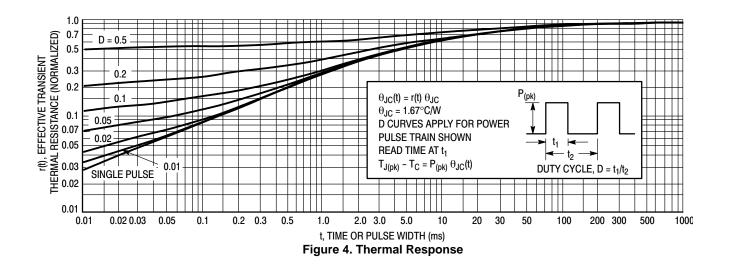
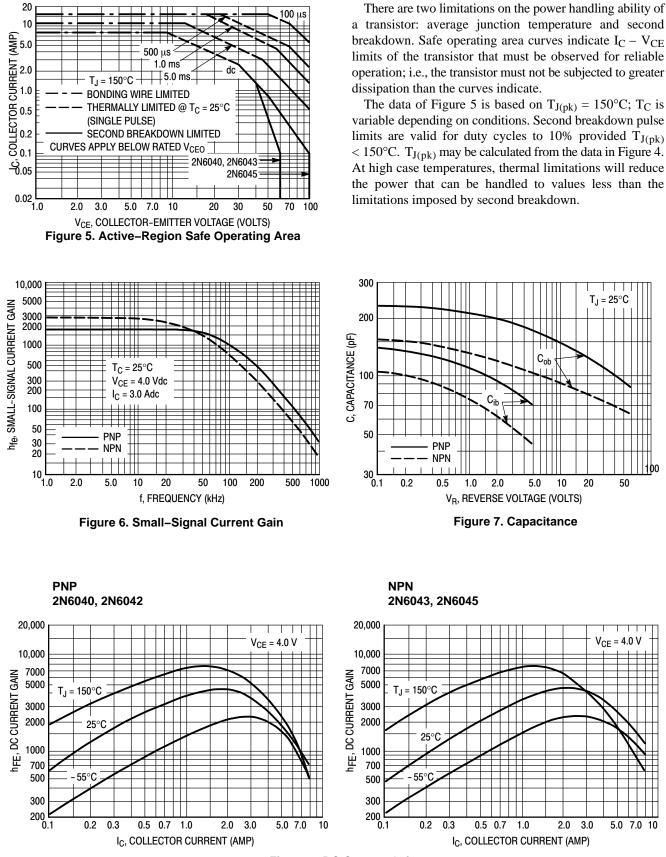


Figure 2. Switching Times Equivalent Circuit

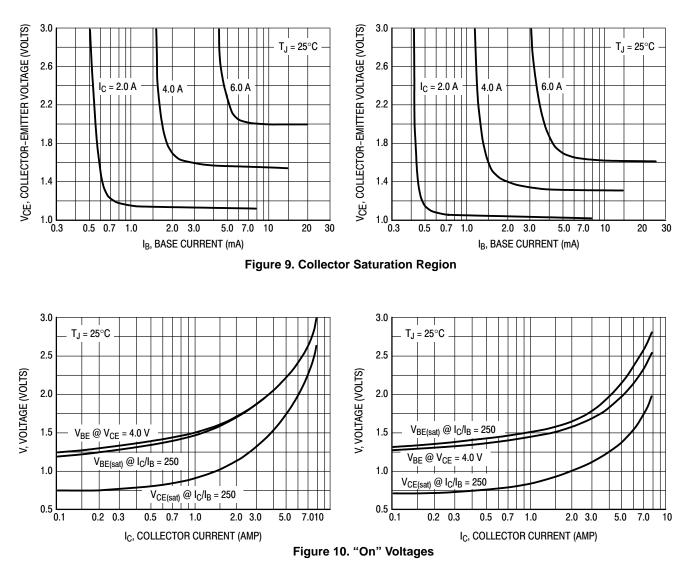
Figure 3. Switching Times







## PNP - 2N6040, 2N6042, NPN - 2N6043, 2N6045

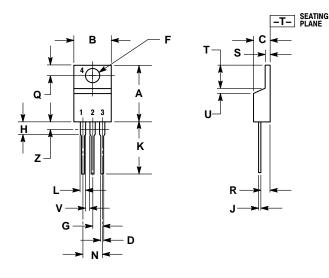


## **ORDERING INFORMATION**

Device	Package	Shipping
2N6040G	TO-220 (Pb-Free)	50 Units / Rail
2N6042G	TO-220 (Pb-Free)	50 Units / Rail
2N6043G	TO-220 (Pb-Free)	50 Units / Rail
2N6045G	TO–220 (Pb–Free)	50 Units / Rail

#### PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AH** 



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.415	9.66	10.53	
С	0.160	0.190	4.07	4.83	
D	0.025	0.038	0.64	0.96	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
н	0.110	0.161	2.80	4.10	
J	0.014	0.024	0.36	0.61	
Κ	0.500	0.562	12.70	14.27	
Г	0.045	0.060	1.15	1.52	
Ν	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
۷	0.045		1.15		
Ζ		0.080		2.04	

STYLE 1: BASE PIN 1. 2. COLLECTOR FMITTER 3 COLLECTOR

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